- **19.2 VOLT NOMINAL ZENER VOLTAGE ± 5%**
- **TEMPERATURE COMPENSATED ZENER REFERENCE DIODES**
- **LOW NOISE**
- **METALLURGICALLY BONDED**
- **DOUBLE PLUG CONSTRUCTION**

1N4916
thru
1N4932A

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C
Storage Temperature: -65°C to +175°C
DC Power Dissipation: 500mW @ +50°C
Power Derating: 4 mW / °C above +50°C

REVERSE LEAKAGE CURRENT

I_R = 15 μA @ 25°C & V_R = 12Vdc

ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise speci½ed.

JEDEC TYPE NUMBER	TEST CURRENT I_{ZT} (Note 3)	VOLTAGE TEMPERATURE STABILITY $^3V_{ZT}$ (Note 2)	TEMPERATURE RANGE	EFFECTIVE TEMPERATURE COEFFICIENT	MAXIMUM DYNAMIC IMPEDANCE Z_{ZT} (Note 1)	MAXIMUM NOISE DENSITY N_D
	mA	mV	°C	%/°C	OHMS	$\mu V \sqrt{Hz}$
1N4916	0.5	144	+25 to +100	0.01	600	1.0
1N4916A	0.5	298	-55 to +100	0.01	600	1.0
1N4917	0.5	72	+25 to +100	0.005	600	1.0
1N4917A	0.5	149	-55 to +100	0.005	600	1.0
1N4918	0.5	29	+25 to +100	0.002	600	1.0
1N4918A	0.5	60	-55 to +100	0.002	600	1.0
1N4919	1.0	144	+25 to +100	0.01	300	0.5
1N4919A	1.0	298	-55 to +100	0.01	300	0.5
1N4920	1.0	72	+25 to +100	0.005	300	0.5
1N4920A	1.0	149	-55 to +100	0.005	300	0.5
1N4921	1.0	29	+25 to +100	0.002	300	0.5
1N4921A	1.0	60	-55 to +100	0.002	300	0.5
1N4922	2.0	144	+25 to +100	0.01	150	0.25
1N4922A	2.0	298	-55 to +100	0.01	150	0.25
1N4923	2.0	72	+25 to +100	0.005	150	0.25
1N4923A	2.0	149	-55 to +100	0.005	150	0.25
1N4924	2.0	29	+25 to +100	0.002	150	0.25
1N4924A	2.0	60	-55 to +100	0.002	150	0.25
1N4925	4.0	144	+25 to +100	0.01	75	0.22
1N4925A	4.0	298	-55 to +100	0.01	75	0.22
1N4926	4.0	72	+25 to +100	0.005	75	0.22
1N4926A	4.0	149	-55 to +100	0.005	75	0.22
1N4927	4.0	29	+25 to +100	0.002	75	0.22
1N4927A	4.0	60	-55 to +100	0.002	75	0.22
1N4928	4.0	14	+25 to +100	0.001	75	0.22
1N4928A	4.0	30	-55 to +100	0.001	75	0.22
1N4929	7.5	144	+25 to +100	0.01	36	0.20
1N4929A	7.5	298	-55 to +100	0.01	36	0.20
1N4930	7.5	72	+25 to +100	0.005	36	0.20
1N4930A	7.5	149	-55 to +100	0.005	36	0.20
1N4931	7.5	29	+25 to +100	0.002	36	0.20
1N4931A	7.5	60	-55 to +100	0.002	36	0.20
1N4932	7.5	14	+25 to +100	0.001	36	0.20
1N4932A	7.5	30	-55 to +100	0.001	36	0.20

NOTE 1 Zener impedance is derived by superimposing on I_{ZT} A 60Hz rms a.c. current equal to 10% of I_{ZT}.

NOTE 2 The maximum allowable change observed over the entire temperature range i.e.,the diode voltage will not exceed the speci½ed mV at any discrete temperature between the established limits, per JEDEC standard No.5.

NOTE 3 Zener voltage range equals 19.2 volts ± 5%.

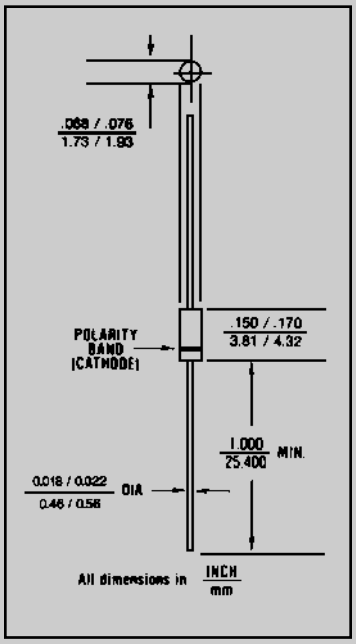


FIGURE 1

DESIGN DATA

CASE: Hermetically sealed glass case. DO – 35 outline.

LEAD MATERIAL: Copper clad steel.

LEAD FINISH: Tin / Lead

POLARITY: Diode to be operated with the banded (cathode) end positive.

MOUNTING POSITION: Any.

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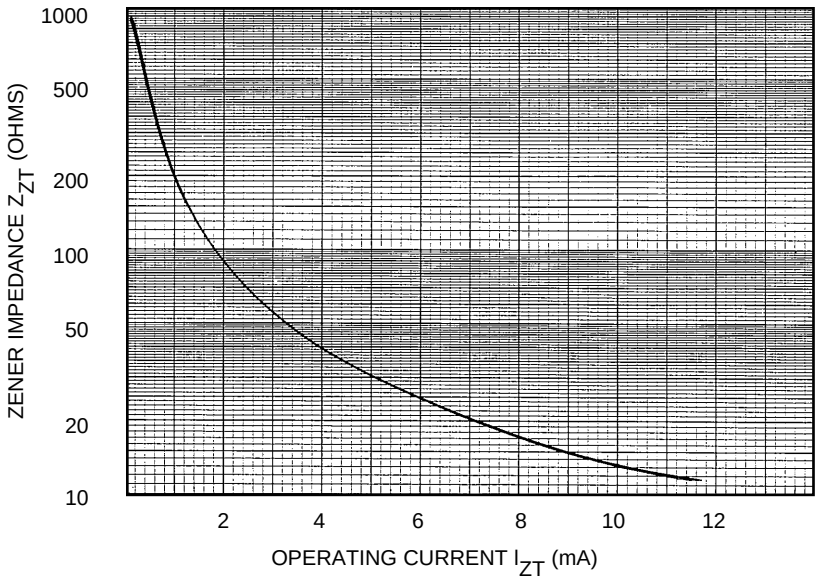


FIGURE 2

ZENER IMPEDANCE VS. OPERATING CURRENT

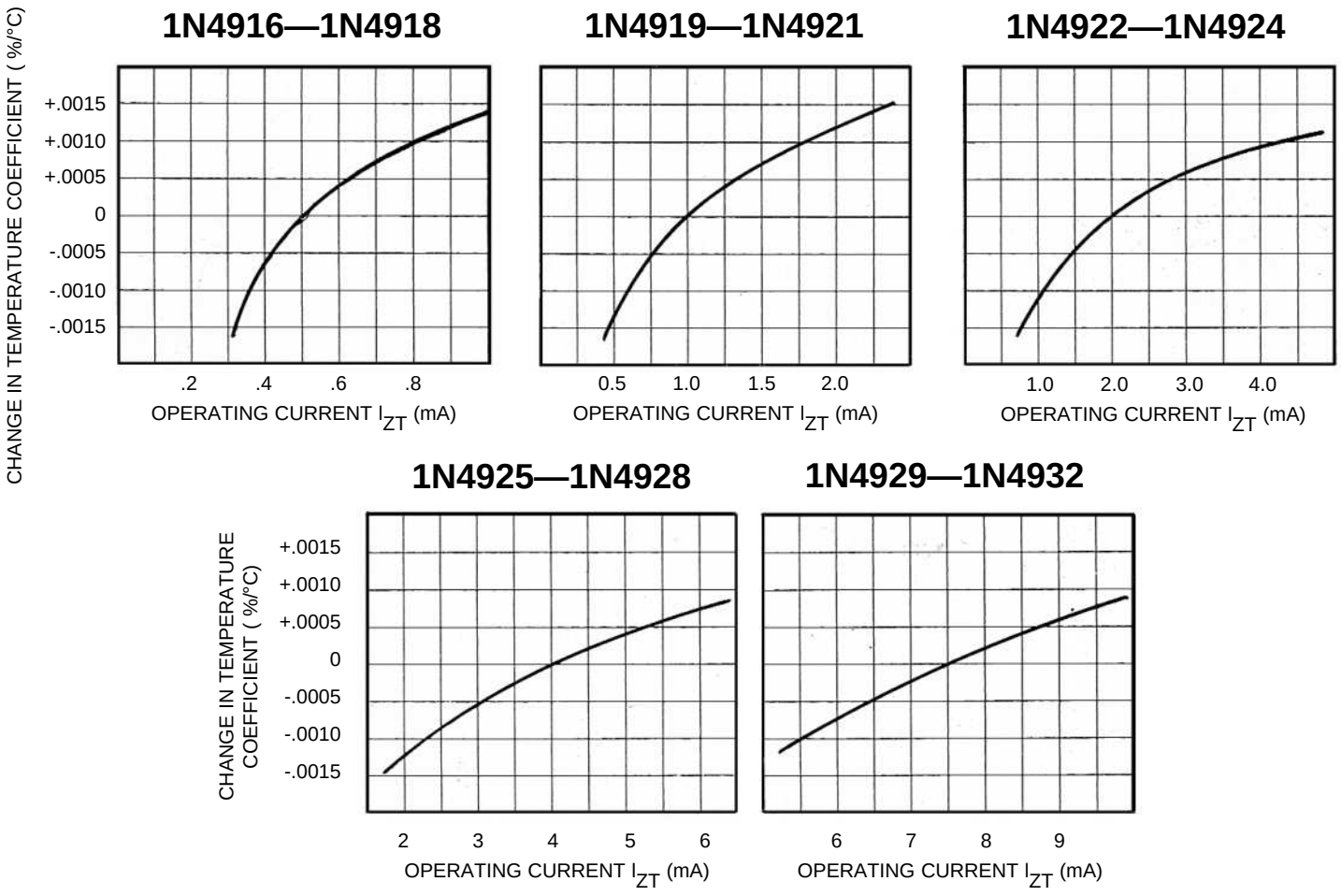


FIGURE 3

TYPICAL CHANGE OF TEMPERATURE COEFFICIENT WITH CHANGE IN OPERATING CURRENT